# NSN 5962-00-530-4660

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-530-4660

## **Body Length:**

Between 0.735 inches and 0.830 inches

## Body Width:

Between 0.245 inches and 0.295 inches

# **Body Height:**

Between 0.055 inches and 0.125 inches

## **Maximum Power Dissipation Rating:**

700.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+85.0 degrees celsius

#### Storage Tempurature Range:

-62.0/+125.0 degrees celsius

#### **Features Provided:**

Monolithic and hermetically sealed and low power and 3-state output and positive outputs

#### **Inclosure Material:**

Ceramic and glass

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

P-type metal oxide-semiconductor logic

#### Input Circuit Pattern:

11 input

### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

20.0 volts power source

#### Memory Device Type:

Rom

#### Memory Capacity:

Unknown

#### **Test Data Document:**

94117-310117 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

--

## Demilitarization:

Yes - demil/mli

# Fiig:

A458a0